Precision, Low Noise, Rail-to-Rail Output, CMOS Operational Amplifier

■ GENERAL DESCRIPTION

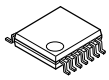
The NJU7076/NJU7077/NJU7078 is a high precision Rail-to-Rail output Single/Dual/Quad CMOS operational amplifier featuring a low noise of 10nV/√Hz typ., low input offset voltage of 150μV max., low temperature drift of 0.5μV/°C typ. and low bias current of 1pA typ..

The output swing can reach 20 mV from the rails, while driving a 10kΩ load (at 5V operation). The NJU7076/NJU7077/ NJU7078 also has a high RF noise immunity which can reduce malfunctions caused by RF noises from mobile phones and others. The combination of these specifications makes the NJU7076/ NJU7077/NJU7078 well-suited for sensor applications such as a temperature sensor, weight sensor and others, high precision current sensing amplifiers and current voltage converters.

■ PACKAGE OUTLINE

NJU7076F
(SOT-23-5)

NJU7077R
(MSOP8(VSP8))



NJU7078V
(SSOP14)

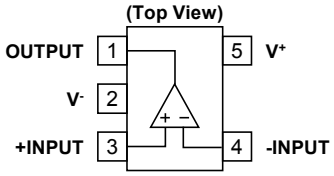
■ FEATURES

- ●High Precision
  - Low Offset Voltage
    - NJU7076/NJU7077: 150μV max.
    - NJU7078: 200μV max.
  - Low Offset Voltage Drift: 0.5μV/°C typ.
- ●Low Noise: 10nV/√Hz typ.
- ●Low Input Bias Current: 1pA typ.
- ●Rail-to-Rail Output
  - R_L=10kΩ: 0.02V to 4.98V typ. (V^+=5V)
  - R_L=600Ω: 0.08V to 4.92V typ. (V^+=5V)
- ●Ground sense
- ●RF Noise Immunity
- ●Operating Voltage: 2.2V to 5.5V
- ●Unity-Gain Stable
- ●Package
  - NJU7076: SOT-23-5
  - NJU7077: MSOP8(VSP8)*
    *MEET JEDEC MO-187-DA
  - NJU7078: SSOP14

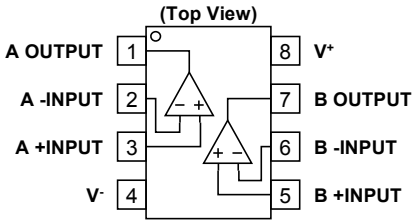
■ APPLICATIONS

- ●Thermocouple / Thermopile Amplifiers
- ●Strain Gauge / Pressure sensor Amplifiers
- ●Load Cell and Bridge Transducer Amplifiers
- ●High Resolution Data Acquisition
- ●Precision Current Sensing
- ●Battery monitoring
- ●Photo-Diode pre amplifier

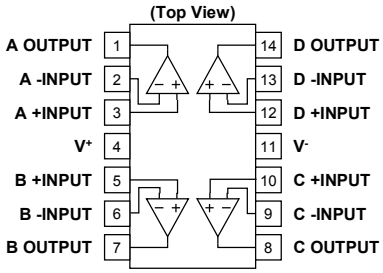
■ PIN CONFIGURATION



NJU7076F



NJU7077R

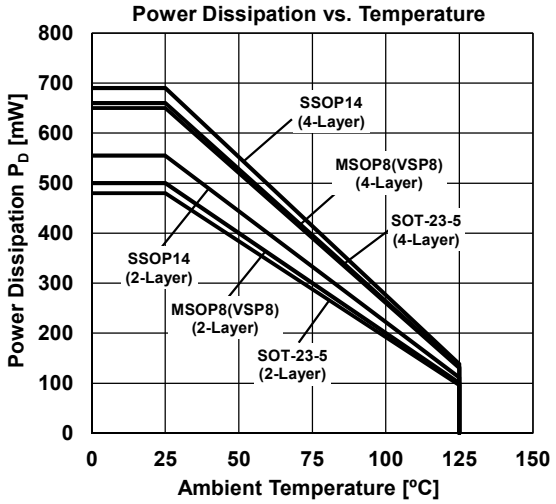


NJU7078V

■ ABSOLUTE MAXIMUM RATINGS(Ta=25˚C, unless otherwise noted.)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V^+- V^-	7 (1)	V
Differential Input Voltage (2)	V_{ID}	±7 (3)	V
Input Voltage	V_{IN}	V^-- 0.3 to V^++ 0.3	V
Power Dissipation (4)	P_D	(2-layer / 4-layer)	mW
SOT-23-5		480 / 650	mW
MSOP8(VSP8)		500 / 660	mW
SSOP14		555 / 690	mW
Operating Temperature Range	T_{opr}	-40 to +125	°C
Storage Temperature Range	T_{stg}	-55 to +150	°C

(1) Supply Voltage is the voltage difference between V^+ and V^-.
(2) Differential voltage is the voltage difference between +INPUT and -INPUT.
(3) For supply voltage less than 7V, the absolute maximum rating is equal to the supply voltage.
(4) Power dissipation is the power that can be consumed by the IC at Ta=25°C, and is the typical measured value based on JEDEC condition. When using the IC over Ta=25°C subtract the value [mW/°C]=PD/(Tstg(MAX)-25) per temperature.
2-layer: EIA/JEDEC STANDARD Test board (76.2x114.3x1.6mm, 2layers, FR-4) mounting
4-layer: EIA/JEDEC STANDARD Test board (76.2x114.3x1.6mm, 4layers, FR-4) mounting



■ RECOMMENDED OPERATING CONDITIONS(Ta=25˚C)

PARAMETER	Value	UNIT
Supply Voltage	+2.2 to +5.5 (±1.1 to ±2.75)	V

■ **ELECTRICAL CHARACTERISTICS**(V^+=5V, V^-=0V, V_{COM}=V^+/2, Ta=25°C, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
DC CHARACTERISTICS						
Input Offset Voltage						
NJU7076/NJU7077	V_{IO}		-	20	150	μV
		Ta=-40°C to 125°C	-	-	400	μV
NJU7078			-	20	200	μV
		Ta=-40°C to 125°C	-	-	400	μV
Input Offset Voltage Drift	$\Delta V_{IO}/\Delta T$	Ta=-40°C to 125°C (5)	-	0.5	5	μV/°C
Input Bias Current	I_B		-	1	-	pA
Input Offset Current	I_{IO}		-	1	-	pA
Open-Loop Voltage Gain	A_V	Vo=0.5V to 4.5V, R_L=10kΩ to 2.5V	100	130	-	dB
		Vo=0.5V to 4.5V, R_L=10kΩ to 2.5V, Ta= -40°C to 125°C	100	-	-	dB
Common-Mode Rejection Ratio	CMR	V_{ICM}=0V to 4V	70	90	-	dB
		V_{ICM}=0V to 4V, Ta= -40°C to 125°C	70	-	-	dB
Supply Voltage Rejection Ratio	SVR	V^+=2.2V to 5.5V	70	90	-	dB
		V^+=2.2V to 5.5V, Ta= -40°C to 125°C	70	-	-	dB
High-level Output Voltage	V_{OH}	R_L=10kΩ to 2.5V	4.95	4.98	-	V
		R_L=10kΩ to 2.5V, Ta= -40°C to 125°C	4.95	-	-	V
		R_L=600Ω to 2.5V	4.85	4.92	-	V
		R_L=600Ω to 2.5V, Ta= -40°C to 125°C	4.85	-	-	V
		I_{SOURCE}=2mA	4.9	4.96	-	V
		I_{SOURCE} =2mA, Ta= -40°C to 125°C	4.85	-	-	V
Low-level Output Voltage	V_{OL}	R_L=10kΩ to 2.5V	-	0.02	0.05	V
		R_L=10kΩ to 2.5V, Ta= -40°C to 125°C	-	-	0.05	V
		R_L=600Ω to 2.5V	-	0.08	0.15	V
		R_L=600Ω to 2.5V, Ta= -40°C to 125°C	-	-	0.2	V
		I_{SINK}=2mA	-	0.04	0.1	V
		I_{SINK}=2mA, Ta= -40°C to 125°C	-	-	0.15	V
Common-Mode Input Voltage Range	V_{ICM}	CMR≥70dB	0	-	4	V
		CMR≥70dB, Ta= -40°C to 125°C	0	-	4	V
Supply Current(All Amplifiers)						
NJU7076	I_{SUPPLY}	No Signal, R_L=OPEN	-	0.6	0.9	mA
		No Signal, R_L=OPEN, Ta = -40°C to 125°C	-	-	0.9	mA
NJU7077		No Signal, R_L=OPEN	-	1.2	1.8	mA
		No Signal, R_L=OPEN, Ta = -40°C to 125°C	-	-	1.8	mA
NJU7078		No Signal, R_L=OPEN	-	2.3	3.5	mA
		No Signal, R_L=OPEN, Ta = -40°C to 125°C	-	-	3.5	mA
AC CHARACTERISTICS						
Gain Bandwidth Product	GBW	G_V=40dB, R_F=100kΩ, R_L=10kΩ to 2.5V, C_L=20pF, f=100kHz	-	1.3	-	MHz
Phase Margin	Φ_m	G_V=40dB, R_F=100kΩ, R_L=10kΩ to 2.5V, C_L=20pF	-	60	-	deg
Gain Margin	G_m	G_V=40dB, R_F=100kΩ, R_L=10kΩ to 2.5V, C_L=20pF	-	12	-	dB
Equivalent Input Noise Voltage	e_n	f=1kHz	-	10	-	nV/√Hz
Slew Rate	SR	G_V=0dB, R_L=10kΩ to 2.5V, C_L=20pF, V_{IN}=3V_{PP}	-	0.5	-	V/μs
Total Harmonic Distortion + Noise	THD+N	G_V=20dB, R_L=10kΩ to 2.5V, f=1kHz, V_O=3V_{PP}	-	0.01	-	%
Channel Separation	CS	f=1kHz, NJU7077/NJU7078	-	140	-	dB

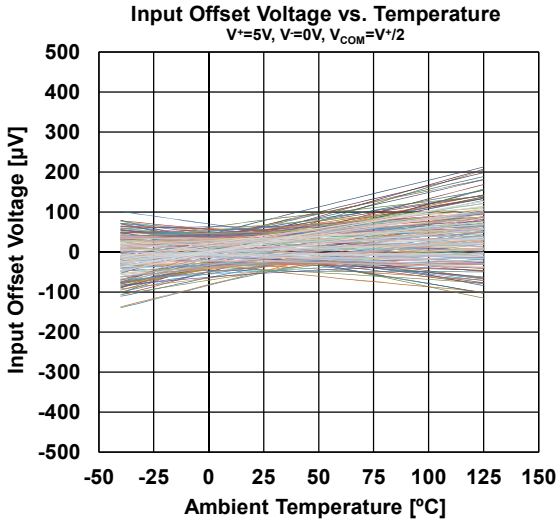
(5) Guaranteed by two points of Temperature -40°C and +125°C

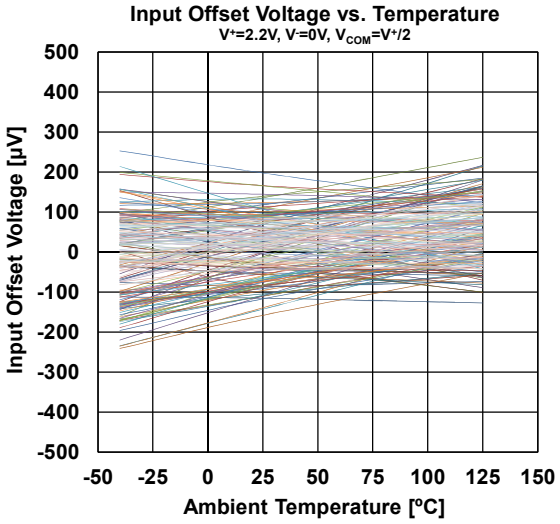
■ **ELECTRICAL CHARACTERISTICS**(V^+=2.2V, V^-=0V, V_{COM}=V^+/2, Ta=25°C, unless otherwise noted.)

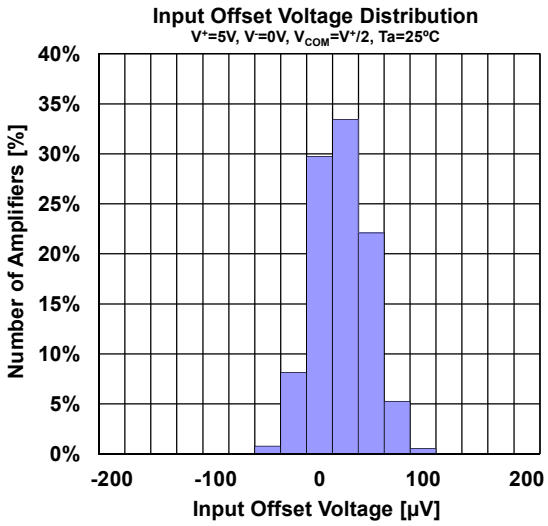
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
DC CHARACTERISTICS						
Input Offset Voltage						
NJU7076/NJU7077			-	60	250	μV
	V_{IO}	Ta= -40°C to 125°C	-	-	400	μV
NJU7078			-	60	300	μV
		Ta= -40°C to 125°C	-	-	400	μV
Input Offset Voltage Drift	$\Delta V_{IO}/\Delta T$	Ta= -40°C to 125°C (5)	-	0.6	5	μV/°C
Input Bias Current	I_B		-	1	-	pA
Input Offset Current	I_{IO}		-	1	-	pA
Open-Loop Voltage Gain	A_V	Vo=0.6V to 1.6V, R_L=10kΩ to 1.1V	100	130	-	dB
		Vo=0.6V to 1.6V, R_L=10kΩ to 1.1V, Ta= -40°C to 125°C	100	-	-	dB
Common-Mode Rejection Ratio	CMR	V_{ICM}=0V to 1.2V	70	90	-	dB
		V_{ICM}=0V to 1.2V, Ta= -40°C to 125°C	70	-	-	dB
High-level Output Voltage	V_{OH}	R_L=10kΩ to 1.1V	2.15	2.18	-	V
		R_L=10kΩ to 1.1V, Ta= -40°C to 125°C	2.15	-	-	V
		R_L=600Ω to 1.1V	2.1	2.14	-	V
		R_L=600Ω to 1.1V, Ta= -40°C to 125°C	2.05	-	-	V
		I_{SOURCE}=2mA	2.05	2.13	-	V
		I_{SOURCE}=2mA, Ta= -40°C to 125°C	2	-	-	V
Low-level Output Voltage	V_{OL}	R_L=10kΩ to 1.1V	-	0.02	0.05	V
		R_L=10kΩ to 1.1V, Ta= -40°C to 125°C	-	-	0.05	V
		R_L=600Ω to 1.1V	-	0.06	0.1	V
		R_L=600Ω to 1.1V, Ta= -40°C to 125°C	-	-	0.15	V
		I_{SINK}=2mA	-	0.07	0.15	V
		I_{SINK}=2mA, Ta= -40°C to 125°C	-	-	0.2	V
Common-Mode Input Voltage Range	V_{ICM}	CMR≥70dB	0	-	1.2	V
		CMR≥70dB, Ta= -40°C to 125°C	0	-	1.2	V
Supply Current(All Amplifiers)						
NJU7076		No Signal, R_L=OPEN	-	0.55	0.82	mA
		No Signal, R_L=OPEN, Ta = -40°C to 125°C	-	-	0.82	mA
NJU7077	I_{SUPPLY}	No Signal, R_L=OPEN	-	1.0	1.5	mA
		No Signal, R_L=OPEN, Ta = -40°C to 125°C	-	-	1.5	mA
NJU7078		No Signal, R_L=OPEN	-	2.0	3.0	mA
		No Signal, R_L=OPEN, Ta = -40°C to 125°C	-	-	3.0	mA
AC CHARACTERISTICS						
Gain Bandwidth Product	GBW	G_V=40dB, R_F=100kΩ, R_L=10kΩ to 1.1V, C_L=20pF, f=100kHz	-	1.2	-	MHz
Phase Margin	Φ_m	G_V=40dB, R_F=100kΩ, R_L=10kΩ to 1.1V, C_L=20pF	-	60	-	deg
Gain Margin	G_m	G_V=40dB, R_F=100kΩ, R_L=10kΩ to 1.1V, C_L=20pF	-	12	-	dB
Equivalent Input Noise Voltage	e_n	f=1kHz	-	10	-	nV/√Hz
Slew Rate	SR	G_V=0dB, R_L=10kΩ to 1.1V, C_L=20pF, V_{IN}=1V_{PP}	-	0.5	-	V/μs
Total Harmonic Distortion + Noise	THD+N	G_V=20dB, R_L=10kΩ to 1.1V, f=1kHz, V_O=1V_{PP}	-	0.01	-	%
Channel Separation	CS	f=1kHz, NJU7077/NJU7078	-	140	-	dB

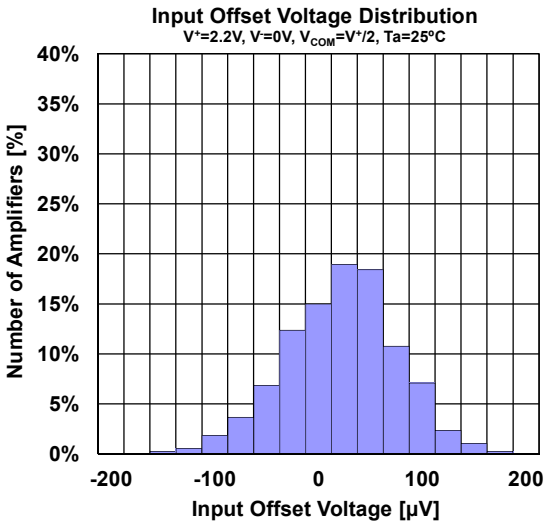
(5) Guaranteed by two points of Temperature -40°C and +125°C

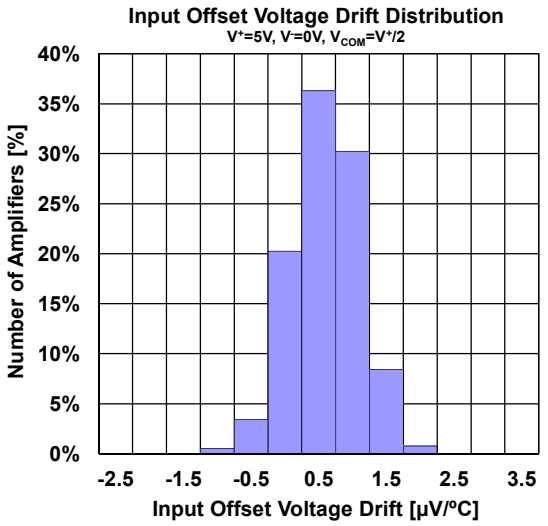
■ TYPICAL CHARACTERISTICS

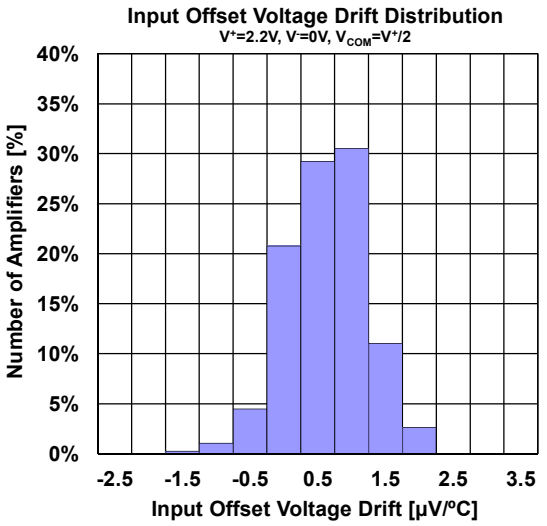






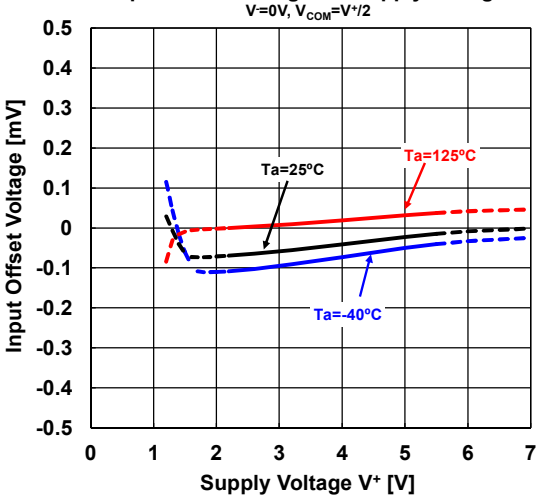




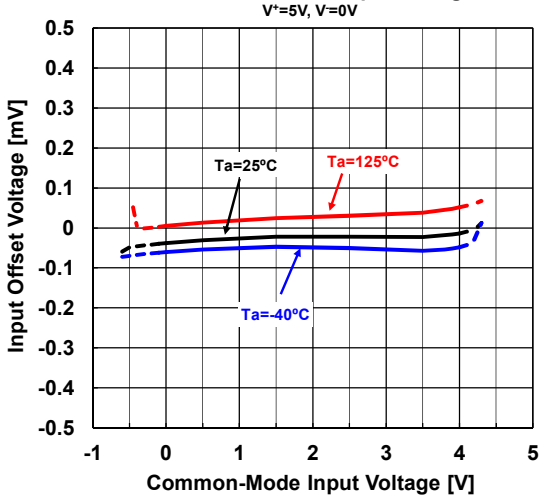


■ TYPIC AL CHARACTERISTICS

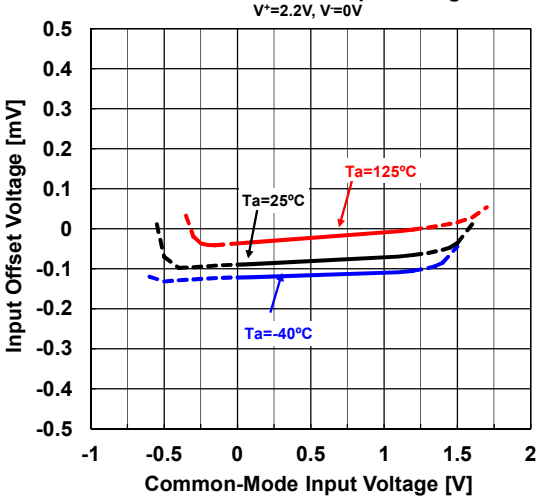
Input Offset Voltage vs. Supply Voltage
V^-=0V, V_{COM}=V^+/2



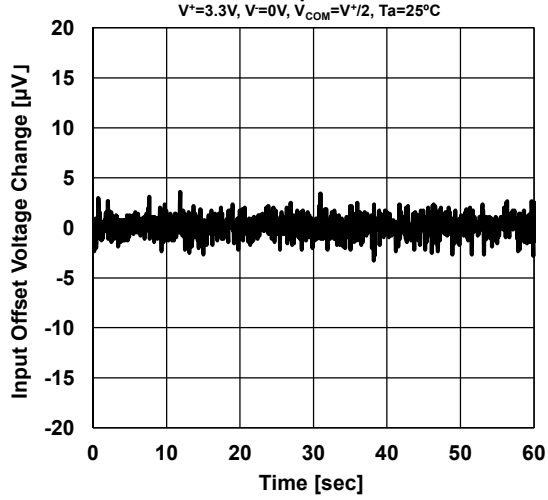
Input Offset Voltage
vs. Common-Mode Input Voltage
V^+=5V, V^-=0V



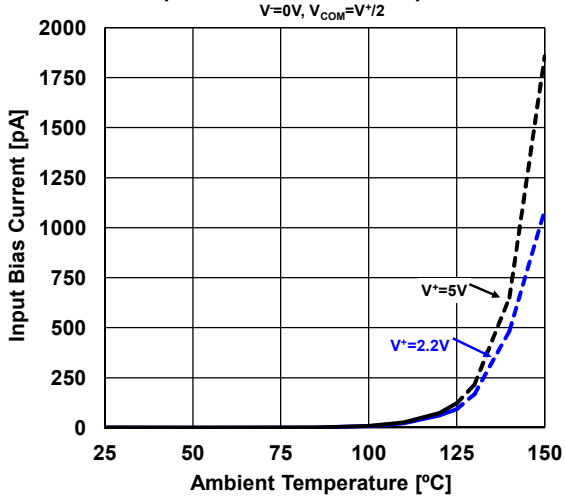
Input Offset Voltage
vs. Common-Mode Input Voltage
V^+=2.2V, V^-=0V



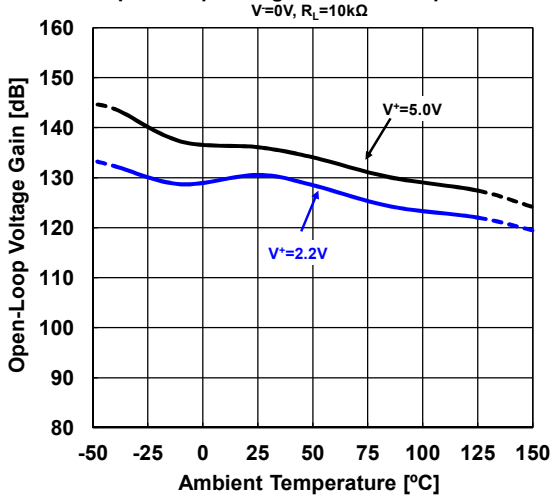
Warm-Up Vio Drift
V^+=3.3V, V^-=0V, V_{COM}=V^+/2, Ta=25ºC



Input Bias Current vs. Temperature
V^-=0V, V_{COM}=V^+/2

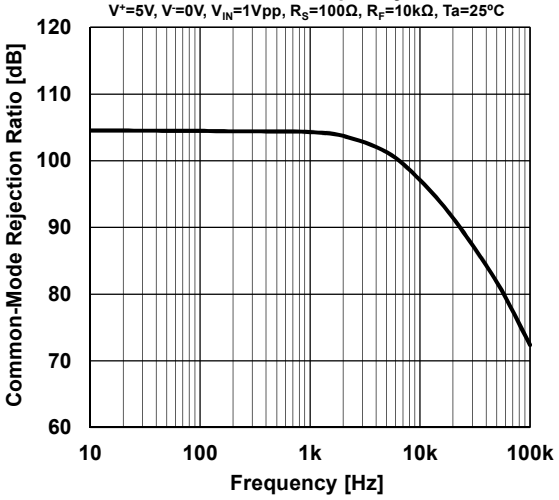


Open-Loop Voltage Gain vs. Temperature
V^-=0V, R_L=10kΩ

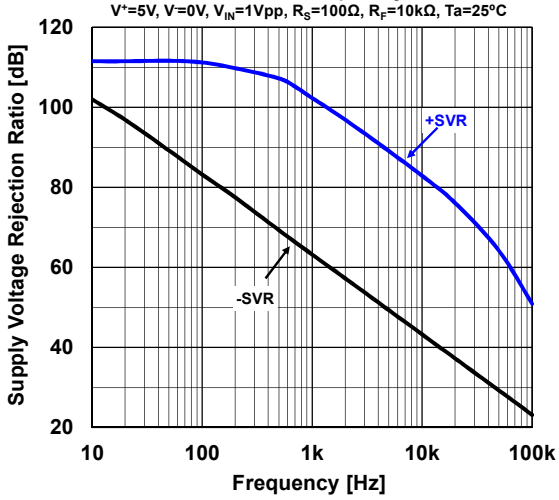


■ TYPICAL CHARACTERISTICS

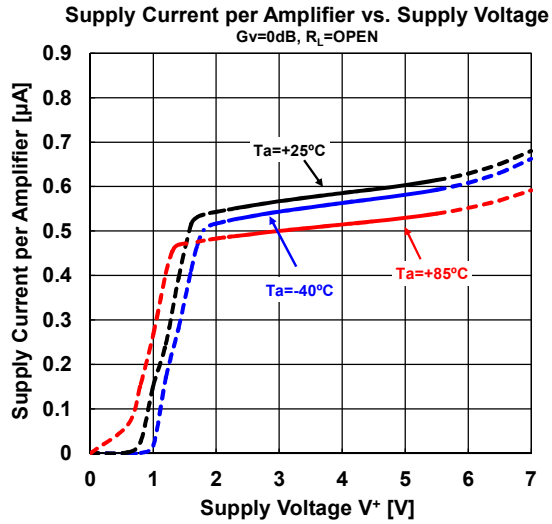
CMR vs. Frequency



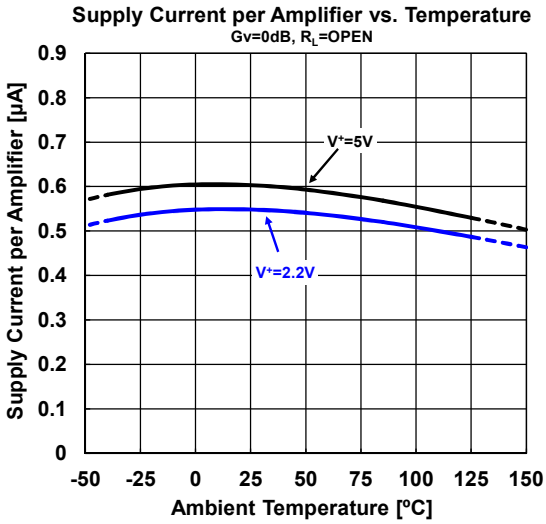
SVR vs. Frequency



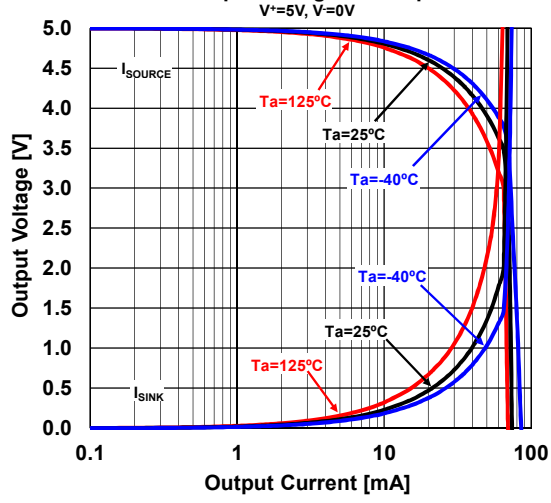
Supply Current per Amplifier vs. Supply Voltage



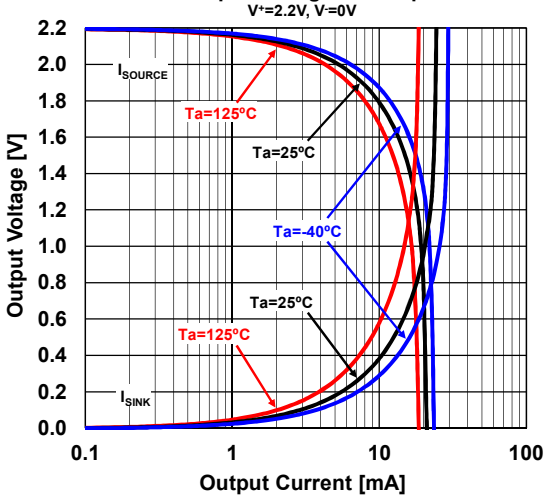
Supply Current per Amplifier vs. Temperature



Maximum Output Voltage vs. Output Current

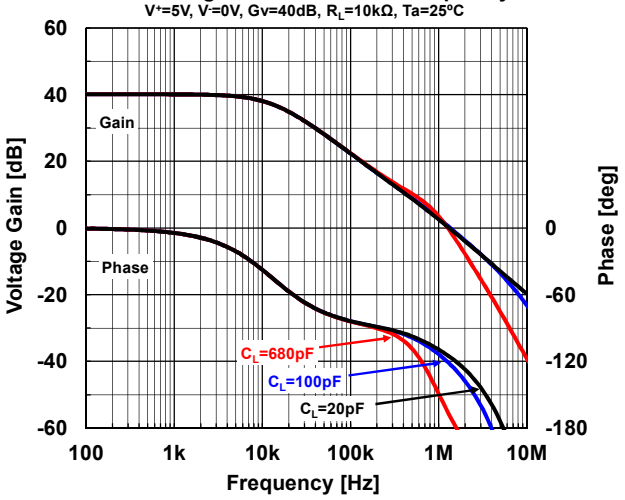


Maximum Output Voltage vs. Output Current

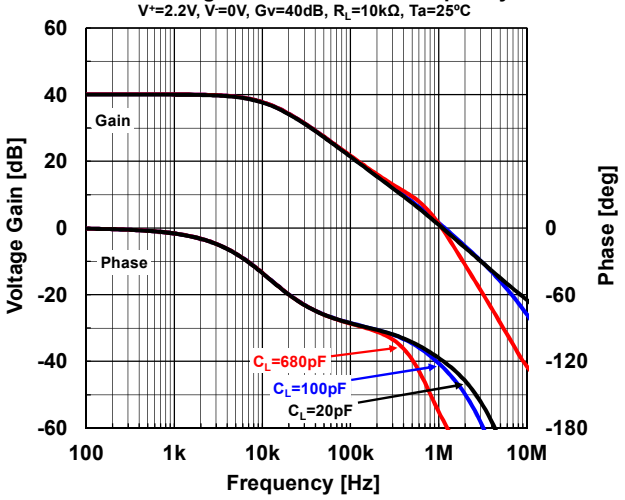


■ TYPICAL CHARACTERISTICS

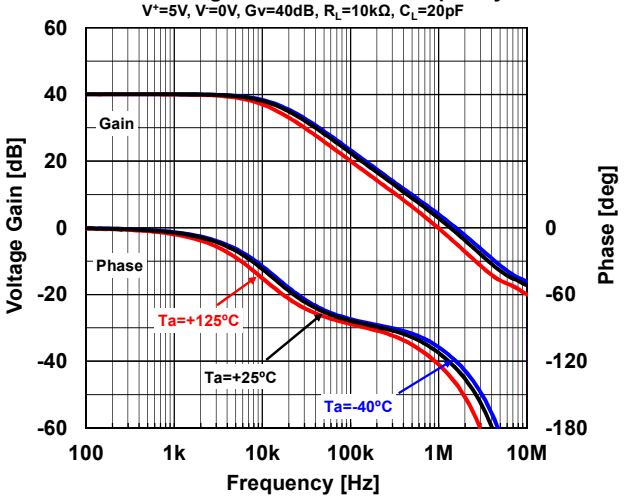
40dB Voltage Gain / Phase vs. Frequency
V+=5V, V-=0V, Gv=40dB, R_L=10kΩ, Ta=25°C



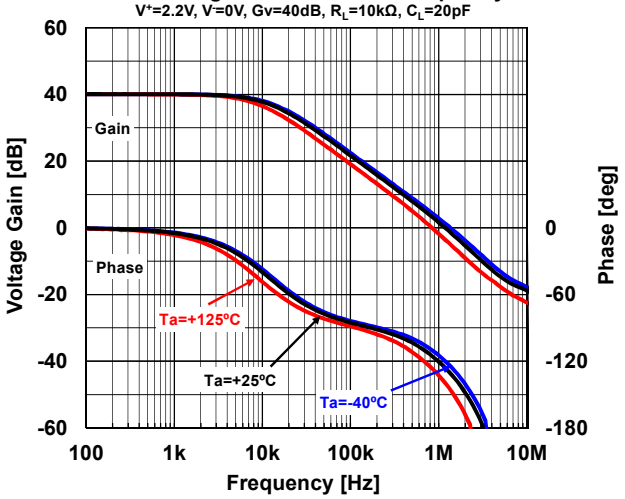
40dB Voltage Gain / Phase vs. Frequency
V+=2.2V, V-=0V, Gv=40dB, R_L=10kΩ, Ta=25°C



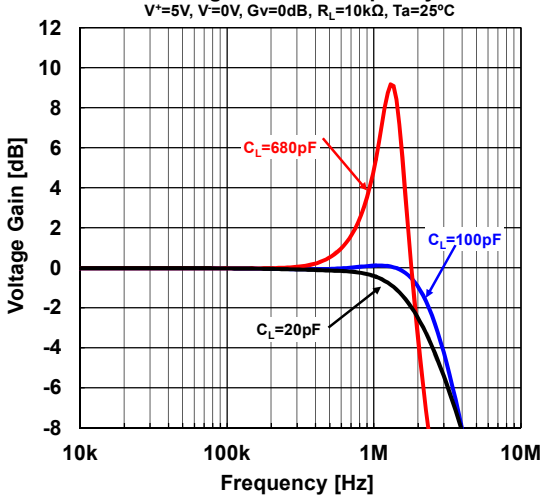
40dB Voltage Gain/Phase vs. Frequency
V+=5V, V-=0V, Gv=40dB, R_L=10kΩ, C_L=20pF



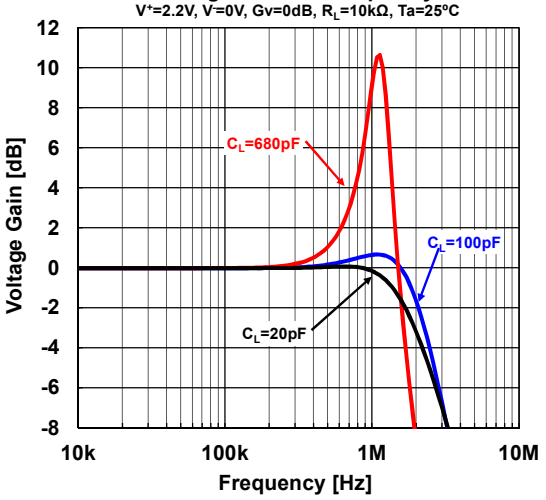
40dB Voltage Gain/Phase vs. Frequency
V+=2.2V, V-=0V, Gv=40dB, R_L=10kΩ, C_L=20pF



Voltage Gain vs. Frequency
V+=5V, V-=0V, Gv=0dB, R_L=10kΩ, Ta=25°C

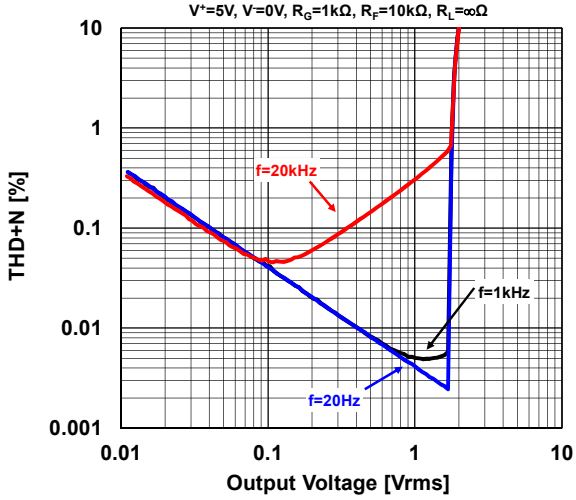


Voltage Gain vs. Frequency
V+=2.2V, V-=0V, Gv=0dB, R_L=10kΩ, Ta=25°C

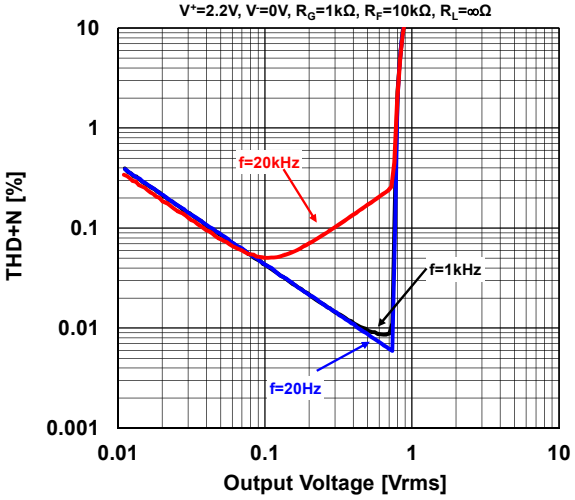


■ TYPICAL CHARACTERISTICS

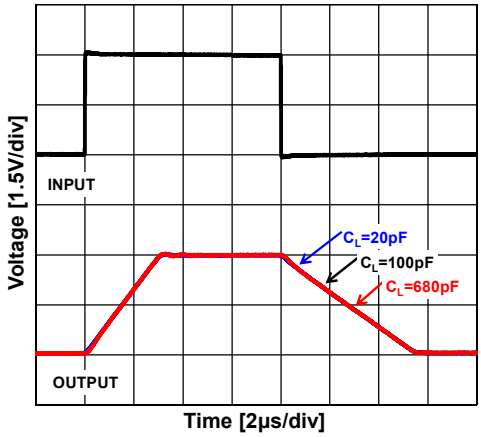
THD+N vs. Output Voltage
V⁺=5V, V⁻=0V, R_G=1kΩ, R_F=10kΩ, R_L=∞Ω



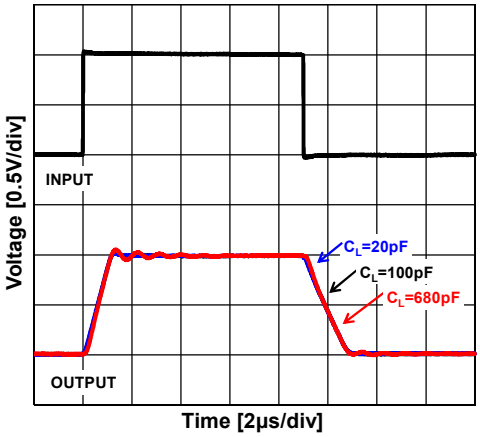
THD+N vs. Output Voltage
V⁺=2.2V, V⁻=0V, R_G=1kΩ, R_F=10kΩ, R_L=∞Ω



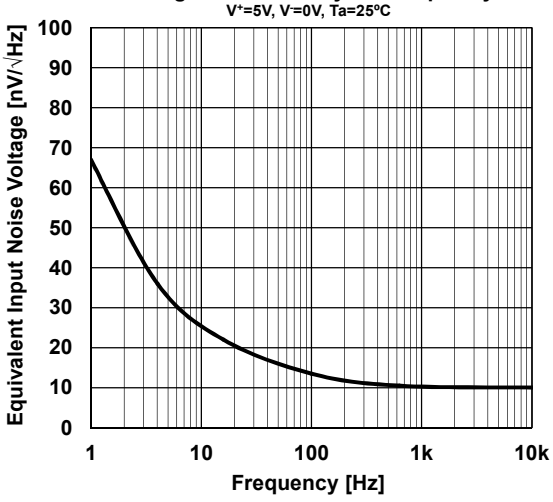
Pulse Response
V⁺=5V, V⁻=0V, R_L=10kΩ, Gv=0dB, Ta=25°C



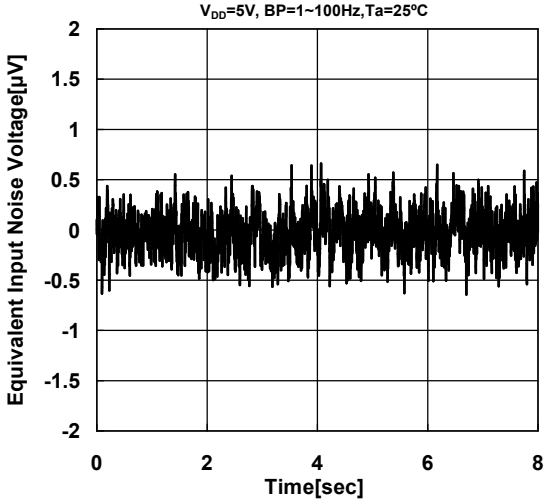
Pulse Response
V⁺=2.2V, V⁻=0V, R_L=10kΩ, Gv=0dB, Ta=25°C



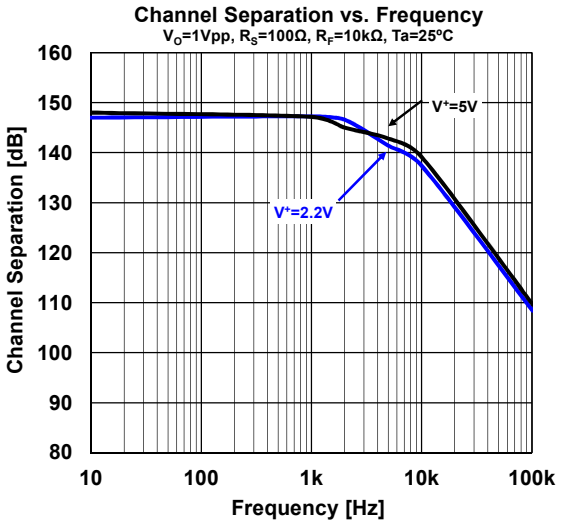
Voltage Noise Density vs. Frequency
V⁺=5V, V⁻=0V, Ta=25°C



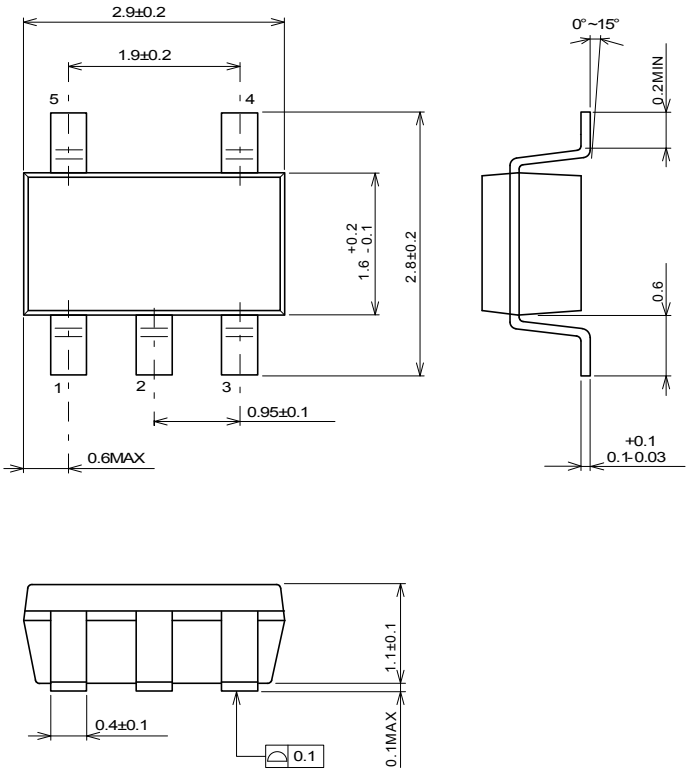
Equivalent Input Voltage Noise
V_{DD}=5V, BP=1~100Hz, Ta=25°C



■ TYPICAL CHARACTERISTICS

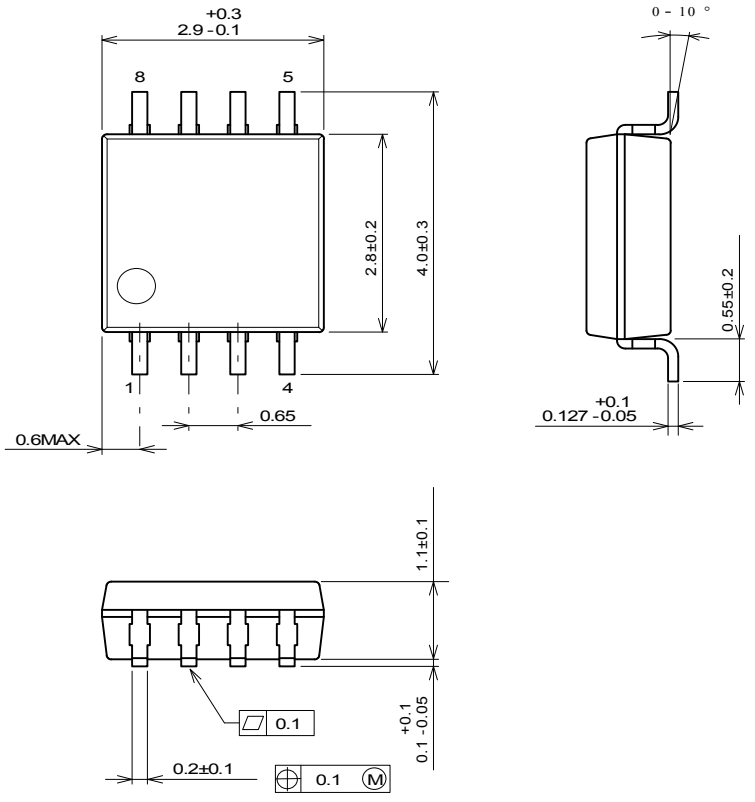


■ **PACKAGE DIMENSIONS**



Unit: mm

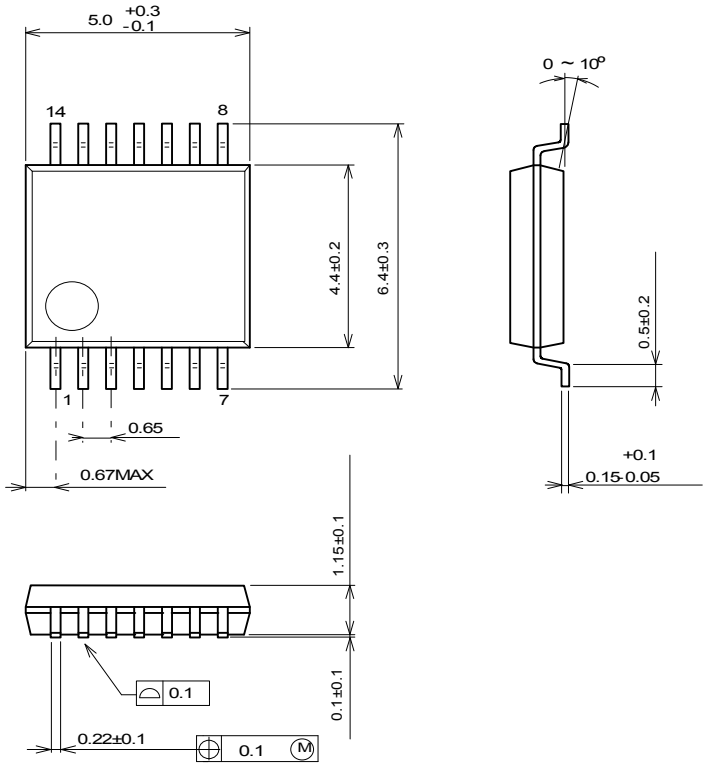
SOT-23-5 Package



Unit: mm

MSOP8(VSP8)* Package
***MEET JEDEC MO-187-DA**

■ **PACKAGE DIMENSIONS**



Unit: mm

SSOP14 Package

Mouser Electronics

Authorized Distributor

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NJR:

NJU7076BF3-TE1 NJU7076F-TE1 NJU7076F-TE2 NJU7078V-TE1